

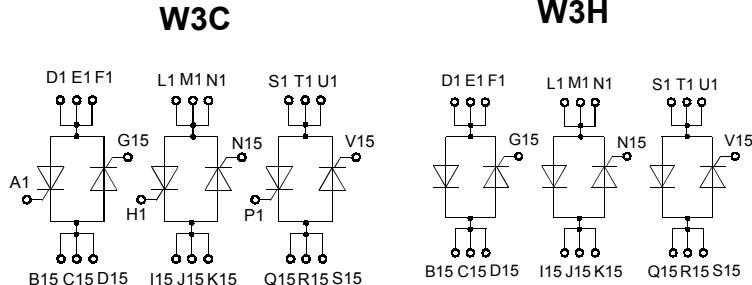
Three Phase AC Controller Modules

PSUT 230
PSUH 230

I_{RMS} = 3 x 200 A
V_{RRM} = 800-1800 V

Preliminary Data Sheet

V _{RSM} V _{DSM} (V)	V _{RRM} V _{DRM} (V)	Type
900	800	PSUT 230/08 PSUH 230/08
1300	1200	PSUT 230/12 PSUH 230/12
1500	1400	PSUT 230/14 PSUH 230/14
1700	1600	PSUT 230/16 PSUH 230/16
1900	1800	PSUT 230/18 PSUH 230/18



Symbol	Test Conditions	Maximum Ratings		
I _{RMS}	T _C = 85 °C; 50-400 Hz (per phase)	200	A	
I _{TRMS}		144	A	
I _{TAVM}	T _C = 85 °C; 180° sine	90	A	
I _{TSM}	T _{VJ} = 45 °C t = 10 ms (50 Hz), sine	2250	A	
	V _R = 0 t = 8.3 ms (60 Hz), sine	2400	A	
	T _{VJ} = 125 °C t = 10 ms (50 Hz), sine	2000	A	
	V _R = 0 t = 8.3 ms (60 Hz), sine	2150	A	
∫ i ² dt	T _{VJ} = 45 °C t = 10 ms (50 Hz), sine	25300	A ² s	
	V _R = 0 t = 8.3 ms (60 Hz), sine	23900	A ² s	
	T _{VJ} = 125 °C t = 10 ms (50 Hz), sine	20000	A ² s	
	V _R = 0 t = 8.3 ms (60 Hz), sine	19100	A ² s	
(di/dt) _{cr}	T _{VJ} = 125 °C repetitive, I _T = 250 A f=50Hz, t _p =200μs V _D =2/3V _{DRM}	150	A/μs	
	I _G =0.45 A non repetitive, I _T = I _{TAVM}	500	A/μs	
	di _G /dt=0.45A/μs			
(dv/dt) _{cr}	T _{VJ} = 125 °C V _D =2/3V _{DRM} R _{GK} = ∞, method 1 (linear voltage rise)	1000	V/μs	
P _{GM}	T _{VJ} = 125 °C t _p =30μs	≤ 10	W	
	I _T =I _{TAVM} t _p =300μs	≤ 5	W	
P _{GAVM}		0.5	W	
V _{RGM}		10	V	
T _{VJ}		-40... + 125	°C	
T _{VJM}		125	°C	
T _{stg}		-40... + 125	°C	
V _{ISOL}	50/60 Hz, RMS t = 1 min	2500	V~	
	I _{ISOL} ≤ 1 mA t = 1 s	3000	V~	
M _d	Mounting torque (M5)	3	Nm	
		26	lb. in.	
Weight	typ.	86	g	

Data according to IEC 60747 refer to a single thyristor unless otherwise stated



typical picture, for pin configuration see outline drawing

Features

- Thyristor controller for AC (circuit W3C acc. to IEC) for mains frequency □
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering
- UL Release applied

Applications

- Switching and control of three phase AC circuits
- Light and temperature control
- Softstart AC motor controller
- Solid state switches

Advantages

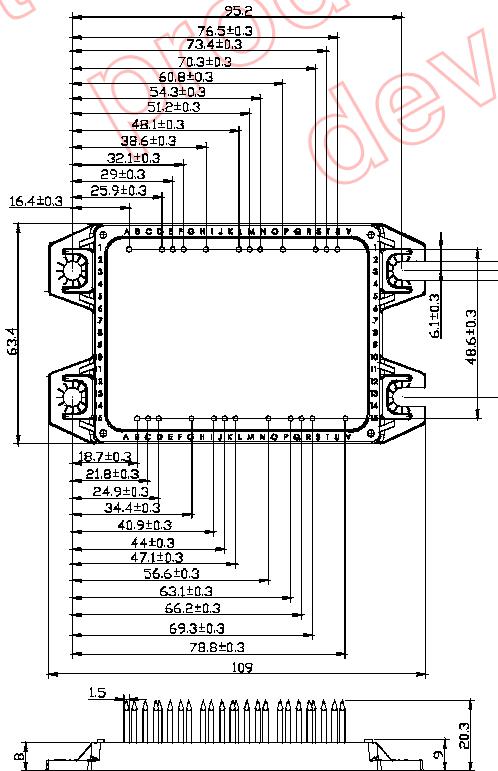
- Easy to mount with four screws
- Space and weight savings
- Improved temperature and power cycling capability
- High power density
- Small and light weight

Symbol	Test Conditions		Characteristic Value		
$I_{D,R}$	$T_{VJ} = 125^\circ C$, $V_R = V_{RRM}$, $V_D = V_{DRM}$	\leq	5	mA	
V_T	$I_T = 300 A$, $T_{VJ} = 25^\circ C$	\leq	1.5	V	
V_{TO}	For power-loss calculations only		0.85	V	
r_T			2.5	$m\Omega$	
V_{GT}	$V_D = 6V$	$T_{VJ} = 25^\circ C$	\leq	1.5	V
		$T_{VJ} = -40^\circ C$	\leq	1.6	V
I_{GT}	$V_D = 6V$	$T_{VJ} = 25^\circ C$	\leq	150	mA
		$T_{VJ} = -40^\circ C$	\leq	200	mA
V_{GD}	$T_{VJ} = 125^\circ C$	$V_D = 2/3V_{DRM}$	\leq	0.2	V
I_{GD}	$T_{VJ} = 125^\circ C$	$V_D = 2/3V_{DRM}$	\leq	10	mA
I_L	$T_{VJ} = 25^\circ C$, $t_p = 10\mu s$	\leq	450	mA	
	$I_G = 0.45A$, $dI_G/dt = 0.45A/\mu s$				
I_H	$T_{VJ} = 25^\circ C$, $V_D = 6V$, $R_{GK} = \infty$	\leq	200	mA	
t_{gd}	$T_{VJ} = 25^\circ C$, $V_D = 1/2V_{DRM}$	\leq	2	μs	
	$I_G = 0.45A$, $dI_G/dt = 0.45A/\mu s$				
R_{thJC}	per thyristor; DC		0.3	K/W	
	per module		0.05	K/W	
R_{thJK}	per thyristor; sine 180° el		0.49	K/W	
	per module		0.082	K/W	
d_s	Creepage distance on surface (Pin to heatsink)	min.	11.2	mm	
d_A	Strike distance in air (Pin to heatsink)	min.	11.2	mm	
a	Max. allowable acceleration		50	m/s^2	

Package style and outline

Dimensions in mm (1mm = 0.0394")

W3C



W3H

